# NSN 5962-01-216-0733

Memory Microcircuit - Page 1 of 1



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# **Body Length:**

Between 0.755 inches and 0.785 inches

## **Body Width:**

Between 0.245 inches and 0.280 inches

## **Body Height:**

0.180 inches

# **Maximum Power Dissipation Rating:**

400.0 milliwatts

## **Operating Tempurature Range:**

-0.0/+70.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## **Features Provided:**

Programmable and schottky and monolithic and bipolar

#### **Inclosure Material:**

# Ceramic and glass

# Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

## Input Circuit Pattern:

6 input

#### **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

7.0 volts power source

## **Time Rating Per Chacteristic:**

35.00 nanoseconds propagation delay time, low to high level output and 35.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Rom

#### **Terminal Type And Quantity:**

16 printed circuit

#### Shelf Life:

N/a

# Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

#### Fiig:

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